Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:

Ceramic and metal

Overall Length:

Between 0.145 inches and 0.161 inches

Overall Diameter:

Between 0.118 inches and 0.124 inches

Function For Which Designed:

Limiter

End Application:

Gpsmagr rf

Mounting Method:

Compression

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

40.0 reverse voltage, peak and 60.0 reverse voltage, peak

Power Rating Per Characteristic:

3.0 watts small-signal output power, common-base minor and 300.0 watts small-signal output power, common-base nanoamperes

Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius junction

Test Data Document:

13499-353-3781 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

2 case

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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